

RELIABILITY REPORT FOR MAX860ISA+ PLASTIC ENCAPSULATED DEVICES

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MAXIM INTEGRATED PRODUCTS

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Conclusion

The MAX860ISA+ successfully meets the guality and reliability standards required of all Maxim products. In addition, Maxim's continuous reliability monitoring program ensures that all outgoing product will continue to meet Maxim's quality and reliability standards.

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I. Device Description

A. General

The MAX860/MAX861 charge-pump voltage converters invert input voltages ranging from +1.5V to +5.5V, or double input voltages ranging from +2.5V to +5.5V. Because of their high switching frequencies, these devices use only two small, low-cost capacitors. Their 50mA output makes switching regulators unnecessary, eliminating inductors and their associated cost, size, and EMI. Greater than 90% efficiency over most of the load-current range, combined with a typical operating current of only 200µA (MAX860), provides ideal performance for both battery-powered and board-level voltage-conversion applications. A frequency-control (FC) pin provides three switching-frequencies to optimize capacitor size and quiescent current and to prevent interference with sensitive circuitry. Each device has a unique set of three available frequencies. A shutdown (active-low SHDN) pin reduces current consumption to less than 1µA. The MAX860/MAX861 are suitable for use in applications where the ICL7660 and MAX660's switching frequencies are too low. The MAX860/MAX861 are available in 8-pin µMax and SO packages.



II. Manufacturing Information

 A. Description/Function:
 50mA, Frequency-Selectable, Switched-Capacitor Voltage Converters

 B. Process:
 S3

Malaysia, Philippines, Thailand

Oregon

Pre 1997

- C. Number of Device Transistors:
- D. Fabrication Location:
- E. Assembly Location:
- F. Date of Initial Production:

III. Packaging Information

A. Package Type:	8-pin SOIC (N)
B. Lead Frame:	Copper
C. Lead Finish:	100% matte Tin
D. Die Attach:	Conductive
E. Bondwire:	Au (1.3 mil dia.)
F. Mold Material:	Epoxy with silica filler
G. Assembly Diagram:	#05-1701-0181
H. Flammability Rating:	Class UL94-V0
I. Classification of Moisture Sensitivity per JEDEC standard J-STD-020-C	Level 1
J. Single Layer Theta Ja:	170°C/W
K. Single Layer Theta Jc:	40°C/W
L. Multi Layer Theta Ja:	132°C/W
M. Multi Layer Theta Jc:	38°C/W

IV. Die Information

A. Dimensions:	58 X 84 mils
B. Passivation:	Si_3N_4/SiO_2 (Silicon nitride/ Silicon dioxide)
C. Interconnect:	Al/0.5%Cu with Ti/TiN Barrier
D. Backside Metallization:	None
E. Minimum Metal Width:	3.0 microns (as drawn)
F. Minimum Metal Spacing:	3.0 microns (as drawn)
G. Bondpad Dimensions:	5 mil. Sq.
H. Isolation Dielectric:	SiO ₂
I. Die Separation Method:	Wafer Saw



A. Quality Assurance Contacts:	Ken Wendel (Director, Reliability Engineering) Bryan Preeshl (Managing Director of QA)
B. Outgoing Inspection Level:	0.1% for all electrical parameters guaranteed by the Datasheet. 0.1% For all Visual Defects.
C. Observed Outgoing Defect Rate:	< 50 ppm
D. Sampling Plan:	Mil-Std-105D

VI. Reliability Evaluation

A. Accelerated Life Test

The results of the 135°C biased (static) life test are shown in Table 1. Using these results, the Failure Rate (λ) is calculated as follows:

 $\lambda = \underbrace{1}_{\text{MTTF}} = \underbrace{1.83}_{192 \times 4340 \times 160 \times 2} \text{ (Chi square value for MTTF upper limit)} \\ \text{(where 4340 = Temperature Acceleration factor assuming an activation energy of 0.8eV)} \\ \lambda = 6.71 \times 10^{-9} \\ \lambda = 6.71 \text{ F.I.T. (60\% confidence level @ 25°C)}$

The following failure rate represents data collected from Maxim"s reliability monitor program. Maxim performs quarterly life test monitors on its processes. This data is published in the Reliability Report found at http://www.maxim-ic.com/qa/reliability/monitor. Cumulative monitor data for the S3 Process results in a FIT Rate of 0.04 @ 25C and 0.69 @ 55C (0.8 eV, 60% UCL)

B. Moisture Resistance Tests

The industry standard 85°C/85%RH or HAST testing is monitored per device process once a quarter.

C. E.S.D. and Latch-Up Testing

The PW48 die type has been found to have all pins able to withstand a HBM transient pulse of +/-2500 V per Mil-Std 883 Method 3015.7. Latch-Up testing has shown that this device withstands a current of +/-250 mA.



Reliability Evaluation Test Results MAX860ISA+						
TEST ITEM	TEST CONDITION	FAILURE	SAMPLE SIZE	NUMBER OF FAILURES		
Static Life Test	(Note 1)					
	Ta = 135°C	DC Parameters	160	0		
	Biased	& functionality				
	Time = 192 hrs.					
Moisture Testing	(Note 2)					
HAST	Ta = 130°C	DC Parameters	77	0		
	RH = 85%	& functionality				
	Biased					
	Time = 96hrs.					
Mechanical Stres	ss (Note 2)					
Temperature	-65°C/150°C	DC Parameters	77	0		
Cycle	1000 Cycles	& functionality				
	Method 1010					

Table 1

Note 1: Life Test Data may represent plastic DIP qualification lots.

Note 2: Generic Package/Process data